

The SD12C is designed to protect voltage sensitive components from ESD and transient events. Excellent clamping capability, low leakage, and fast response time, make this part ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications.



Specification Features:

- Peak Power 350 W (8 x 20цs)
- Low Leakage
- Low Clamping Voltage
- Small Package for use in Portable Electronics
- Meets IEC61000-4-2 Level 4
- Meets IEC6100-4-4 Level 4
- Meets 16 kV Human Body Model ESD Requirements
- These Devices are Pb–Free and are RoHS Compliant

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic Epoxy Meets UL 94, V⁻0 MOUNTING POSITION: Any QUALIFIED MAX REFLOW TEMPERATURE: 260°C Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 20 μs @ $T_L \leq 25^\circ C$	P _{pk}	350	W
IEC 61000–4–2 (ESD) Air Contac		±30 ±30	kV
IEC 61000–4–4 (EFT)		40	А
Total Device Dissipation FR–5 Board, (Note 1) @ T _A = 25°C Derate above 25°C	P _D	200 1.5	mW mW/°C
Thermal Resistance from Junction-to-Ambient	R_{\thetaJA}	635	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Minimum Solder Footprint.

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THINK CHANGE

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ IPP		
V _{RWM}	Working Peak Reverse Voltage		
I _R	Maximum Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
Ι _Τ	Test Current		
ΘV_{BR}	Maximum Temperature Variation of V _{BR}		



ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$, unless otherwise specified)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Reverse Working Voltage	(Note 2)	V _{RWM}		12	V	
Breakdown Voltage	I _T = 1 mA, (Note 3)	V _{BR}	13.3			V
Reverse Leakage Current	V _{RWM} = 12 V	I _R			1.0	μΑ
Clamping Voltage Additional Clamping Voltage	I_{PP} = 5 A, (8 x 20 µsec Waveform) I_{PP} = 15 A, (8 x 20 µsec Waveform)	V _C			19 24	V
Maximum Peak Pulse Current	8 x 20 µsec Waveform	I _{PP}			15	А
Capacitance	V _R = 0 V, f = 1 MHz	Cj		64		pF
	V _R = 12 V, f = 1 MHz			36		1

TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
V_{BR} is measured at pulse test current I_T.



Outline Drawing - SOD-323







DIMENSIONS					
SYMBOL	MILLIMETER		INCHES		
OTNIDOL	MIN	MAX	MIN	MAX	
А	1.600	1.800	0.063	0.071	
В	0.250	0.350	0.010	0.014	
С	2.500	2.700	0.098	0.106	
D		1.000		0.039	
E	1.200	1.400	0.047	0.055	
F	0.080	0.150	0.003	0.006	
L	0.475 REF		0.019	REF	
L1	0.250	0.400	0.010	0.016	
Н	0.000	0.100	0.000	0.004	

Marking



Ordering information

Order code	Package	Baseqty	Delivery mode
SD12CT1G	SOD-323	3000	Tape and reel